

iStar sCMOS

Fast gated sCMOS solutions

Ultrafast Platform for Nanosecond Time-resolved Imaging



Key Specifications

- 5.5 megapixel sCMOS
- 50 fps full frame
- High dynamic range at full speed
- Integrated triple output DDG
- Photocathode QE up to 50%
- Integrate-On-Chip gating up to 500 kHz
- USB 3.0 interface

Key Applications

- ✓ Plasma studies
- ✓ Time-resolved Fluorescence / Photoluminescence
- ✓ PLIF imaging / Combustion studies
- ✓ Hyperspectral Imaging

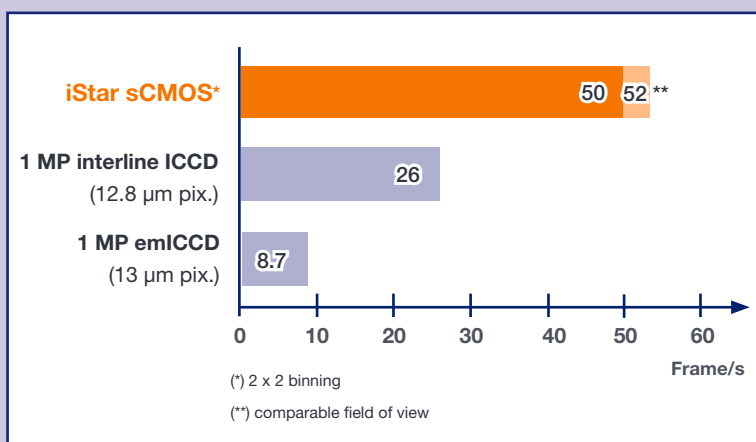
iStar sCMOS – Ultrafast acquisition speeds



Superior **high-speed** acquisition performance

- ✓ 12-bit high-speed mode
- ✓ **2 times faster** than the closest interline-based competitor at an equivalent field-of-view (and over 5 times faster with ROI)

Market leading acquisition rates...



| Image Array Size | Frame Rate 12-bit (16-bit)*1 |
|--------------------------------|------------------------------|
| 2560 x 2160 | 50 (50) |
| 2048 x 2048 | 52 (52) |
| 2160 x 1800 [Ø 18 mm tube fit] | 59 (59) |
| 512 x 512 | 203 (203) |
| 128 x 128 | 736 (736) |
| 2560 x 8 | 4,008 (4,008) |

Delivers:

- ✓ Faster characterisation of transient plasma, fluorescence or absorption behaviours
- ✓ Faster Echellograme image capture for broadband LIBS-based applications

PLIF Imaging / Combustion

iStar sCMOS comfortably accommodates the 15 Hz imaging requirement of typical PLIF setups with extremely low noise floor and excellent dynamic range, nanosecond snapshots of the flame and high background light rejection.

Optical inter-frame down to 200 ns for time-gated PIV setups with a wide range of velocities.

Plasma Imaging

The high frame rate and < 2 ns gating of the iStar sCMOS allow faster reconstruction of plasma dynamics with extremely high temporal resolution.

GPU Express for real time data processing.

GPU Express




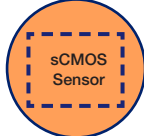
The Andor GPU Express library has been created to simplify and optimize data transfers from camera to a CUDA-enabled NVidia Graphical Processing Unit (GPU) card to facilitate accelerated GPU processing as part of the acquisition pipeline. GPU Express integrates easily with SDK3 for Windows, providing a user-friendly but powerful solution for management of high bandwidth data flow challenges.

- Enhanced convenience, afforded by simple, optimized GPU data management.
- Optimal data throughput.
- Superb, easily accessible documentation and examples.

Features & Benefits

| Feature | Benefit |
|---|---|
| 50 frames/s acquisition rates | Sustainable rate at full field-of-view, out-performs CCD and interline-based ns gated ICCDs with equivalent field-of-view. |
| 16.6 x 14.0 mm sensor matrix | Large field of view, access more of the useful active area of Ø18 mm image intensifiers without the need for optical tapers. |
| 2.6 e ⁻ read noise | Highest dynamic range even at the fastest frame rates, up to 5 times better performance than the closest interline-based competitor |
| 12-bit and 16-bit modes | 12-bit mode for smaller file size and absolute fastest frame rates, 16-bit for full dynamic range. |
| Up to 32-bit data transmission to PC | On-head intelligence to preserve dynamic range in extensive pixel binning, or high intensity pixel binning scenarios. |
| Optical inter-frame down to 300 ns | Ideal for PIV-type applications requiring fast dual images snapshots with high background rejection or supersonic flow analysis. The true Global Shutter mode facilitates an optical inter-frame gap down to 100 ns, although the intensifier phosphor decay time is the limiting factor. The decay time of a fast P46 phosphor is typically 200 ns (@ 10% intensity). |
| TE cooling down to 0°C | Efficiently minimizes dark current noise for acquisitions requiring longer sensor exposure time, e.g. integrate-on-chip mode. |
| High QE Gen 2 & 3 image intensifiers | Superior photon capture, with peak QE up to 50% and spectral coverage from 120 to 1,100 nm. |
| True optical gating < 2 ns | Billionth of a second time-resolution for accurate transient phenomena study. |
| Low jitter, on-board Digital Delay Generator (DDG™) | Highest gating timing accuracy with lowest propagation delay. Software controlled 3x triggering outputs with 10 ps setup accuracy for complex experiment integration. |
| 500 kHz sustained photocathode gating | Maximizes signal-to-noise ratio in high repetition rate pulse laser-based applications. |
| Photocathode EBI minimization | Dry gas purge interface for further efficient EBI reduction. |
| Intelligate™ | Intelligent and accurate MCP gating for better than 1:10 ⁸ shuttering efficiency in the UV (Gen 2 image intensifier). |
| USB 3.0 interface | Super-fast data transfer at 40 fps full frame with a plug-and-play, user-friendly interface – optical extenders available for operation up to 100 m. |
| GPU Express | Simplify and optimize data transfers from camera to Graphical Processing Unit (GPU) card to facilitate accelerated GPU processing as part of the acquisition pipeline. |
| Integrated in EPICS | Ease of operation in EPICS software-based facilities such as partner particle accelerators and other large scientific experiments. |
| 2 year warranty | Reliability and guaranteed performance over time. |

Technical Specifications²

| | | |
|---|--|--|
| Sensor type | Front-Illuminated Scientific CMOS | |
| Sensor matrix | 2560 x 2160 pixels (W x H), 6.5 µm pixel size | |
| | <p>Ø18 mm intensifier</p>  <p>1:1 coupler</p> | <p>Ø25 mm intensifier</p>  <p>1:1 coupler</p> |
| Sensor size | 16.6 x 14.0 mm 21.8 mm diagonal | |
| Pixel well depth (e ⁻) | 30,000 | |
| Read noise (e ⁻) median [rms] at available pixel readout rates ³ | @ 200 MHz 2.4 [2.7] @ 560 MHz 2.6 [2.9] | |
| Minimum cooling temperature ⁴ [dark current, e ⁻ /pixel/s] | Ø18 mm photocathode | Ø25 mm photocathode |
| air cooled | 0°C [0.18] | 0°C [0.18] |
| liquid cooled | 0°C [0.18] | 0°C [0.18] |
| Sensor linearity (% maximum) ⁵ | Better than 99.8% | |
| Data range | 12-bit (fastest speed) and 16-bit (maximum dynamic range) | |
| Pixel binning | On-head, pre-defined options 2x2, 4x4 ... or flexible configuration setup | |
| Region of Interest | Minimum channel height of 8 rows | |
| Interface option | USB 3.0 | |
| Internal memory | 1 GB | |

Camera and Internal Digital Delay Generator (DDG) Inputs/Outputs

| | |
|---------------------------------|--|
| Gate pulse delay & width | Adjustable from 0 ns to 10 s in 10 ps steps |
| Trigger Outputs | |
| Output A, B and C | +5V CMOS level with 50 Ω source impedance; can drive 5V into a non-terminating load or 2.5V into 50 Ω load; output synchronized triggers for auxiliary equipment, e.g. lasers, flash lamps, National Instrument™ hardware Individual delays control from 0 ns to 10 s in 10 ps steps Configurable Polarity |
| Fire | 5V CMOS level reference signal for beginning and end of individual sensor exposure |
| Arm monitor | 5V CMOS level reference signal to indicate when system is ready to accept external triggers. Signal goes high when system is ready to accept external triggers (after a readout has finished or sooner if in overlap mode) and goes low when the exposure is finished |
| Gate & output A, B and C jitter | 35 ps rms (relative to external trigger or to each other) |
| Trigger Inputs | |
| External trigger | Trigger input for sensor and Digital Delay Generator Up to 500 kHz for Integrate-On-Chip mode |
| Direct gate | TTL input for exact external control of photocathode width and timing with smallest insertion delay |
| Additional Controls | |
| Gate monitoring | AC coupling from photocathode to monitor exact photocathode on/off switching and timings |
| Insertion delay | < 19 ns in direct gate operation |

Specifications: Gen 2 image intensifiers*2

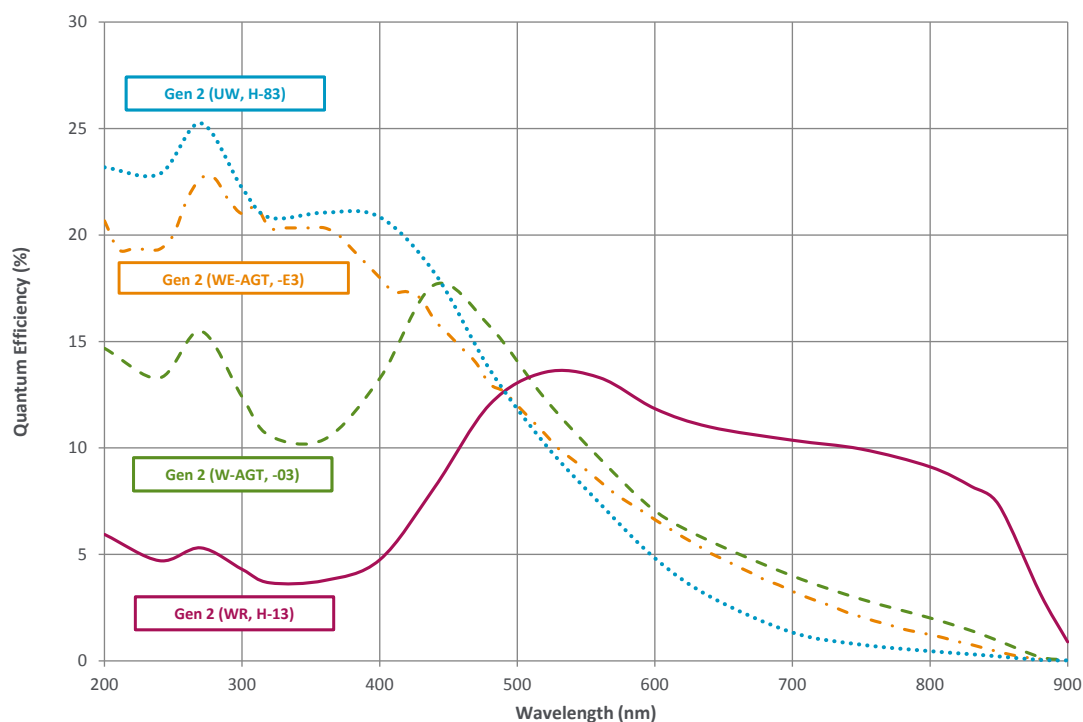
| Photocathode model | 18*-03 | 18*-04 | 18*-05 † | 18H-13 | 18H-83 | 18*-E3*6 |
|--|--|--------------|-----------------------|--------------|-----------------------|--------------|
| Useful aperture | Ø18 mm (Ø25 mm options also available) | | | | | |
| Input window | Quartz | Quartz | MgF ₂ | Quartz | Quartz | Quartz |
| Photocathode type | W-AGT | W-AGT | W-AGT | WR | UW | WE-AGT |
| Minimum guaranteed peak QE @ room temperature *7 | 18 | 18 | 15 | 13.5 | 25 | 22 |
| Wavelength range | 180 - 850 nm | 180 - 850 nm | 120 - 850 nm | 180 - 920 nm | 180 - 850 nm | 180 - 850 nm |
| Image intensifier resolution limit *8 | 25 µm | 30 µm | 25 µm | 25 µm | 25 µm | 25 µm |
| Phosphor type [decay time to 10%] | P43 [2 ms] | P46 [200 ns] | P43 [2 ms] | P43 [2 ms] | P43 [2 ms] | P43 [2 ms] |
| Minimum optical gate width (ns) *9, 10 | | | | | | |
| U (Ultrafast) | < 2 | < 2 | < 5 | - | - | < 2 |
| F (Fast) | < 5 | < 5 | < 10 | - | - | < 5 |
| H (High QE) | - | - | - | < 50 | < 100 | - |
| Maximum relative gain *11 | > 1000 | > 500 | > 1000 | > 850 | > 500 | > 300 |
| Maximum photocathode repetition rate (with Intelligate™ OFF) | 500 kHz (continuous) | | | | | |
| Maximum photocathode repetition rate (with Intelligate™ ON) | 5 kHz (continuous) | | | | | |
| Equivalent Background Illuminance (EBI) | < 0.2 photoe-/pix/sec | | < 0.4 photoe-/pix/sec | | < 0.2 photoe-/pix/sec | |

All photocathode types can be combined with a fast-decay P46 phosphor – please contact your local Andor representative for further information

* Substitute with appropriate gate width option, e.g. 18F-03 (please refer to page 8 for detailed ordering information)

† Available with VUV-compatible spectrograph interface

Quantum Efficiency Curves for Gen 2 Image Intensifiers*7

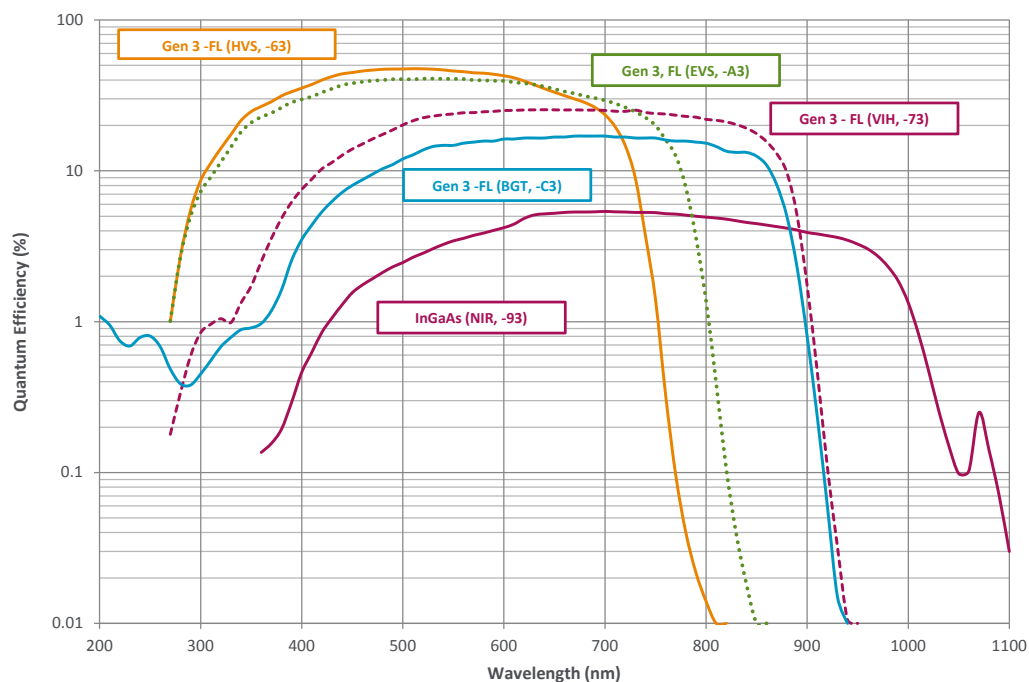


Specifications: Gen 3 image intensifiers*²

| Photocathode model | 18*-63 | 18*-73 | 18*-93 | 18*-A3 | 18*-C3 * ¹² |
|--|---|----------------------|--------------------|----------------------|----------------------------------|
| Useful aperture | Ø 18 mm (Ø25 mm options also available) | | | | |
| Input window | Glass | Glass | Glass | Glass | MgF ₂ + F/O + Lumogen |
| Photocathode type | HVS | VIH | NIR | EVS | BGT |
| Peak QE @ room temperature * ⁷ | > 47.5 | > 25.5 | > 5 | > 40 | > 17 |
| Wavelength range | 280 - 760 nm | 280 - 910 nm | 380 - 1090 nm | 280 - 810 nm | < 200 - 910 nm |
| Image intensifier resolution limit * ⁸ | 30 µm | 30 µm | 30 µm | 30 µm | 40 µm |
| Phosphor type [decay time to 10%] | P43 [2 ms] | | | | |
| Minimum optical gate width (ns) * ¹⁰ | | | | | |
| U (Ultrafast) | < 2 | < 2 | < 3 | < 2 | < 3 |
| F (Fast) | < 5 | < 5 | < 5 | < 5 | < 5 |
| Maximum relative gain * ¹¹ | > 200 | | | | |
| Maximum photocathode repetition rate (with Intelligate™ OFF) | 500 kHz (continuous) | | | | |
| Maximum photocathode repetition rate (with Intelligate™ ON) | 5 kHz (continuous) | | | | |
| Equivalent Background Illuminance (EBI) | < 0.1 photoe/pix/sec | < 0.3 photoe/pix/sec | < 2 photoe/pix/sec | < 0.2 photoe/pix/sec | < 0.3 photoe/pix/sec |

All photocathode types can be combined with a fast-decay P46 phosphor – please contact your local Andor representative for further information
* Substitute with appropriate gate width option, e.g. 18U-63 (please refer to page 8 for detailed ordering information)

Quantum Efficiency Curves for Gen 3 Image Intensifiers*^{7, 12}

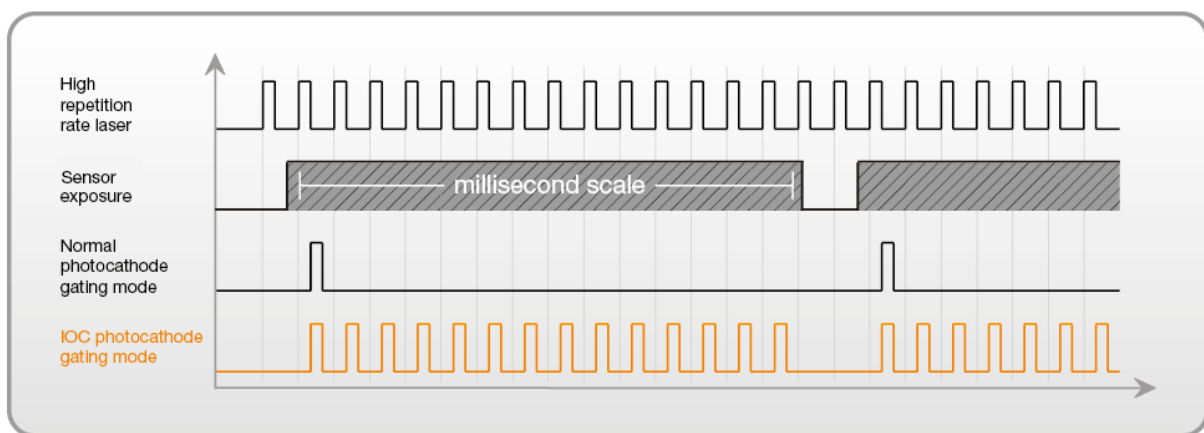


Intelligent gating modes

Integrate-On-Chip: 500,000 times more signal per 1 sec sensor exposure

The iStar's Integrate-On-Chip (IOC) mode enables accumulation of useful signal from laser-induced phenomena at frequencies up to 500 kHz, providing greatly improved signal-to-noise, and minimising experiment time. The latter greatly benefits setups where photobleaching-sensitive biological samples are probed. This translates into the possibility to accumulate 500,000 times more signal per 1 second sensor exposure time.

Integrate-On-Chip is fully software-configurable and can be used through extensive kinetic series involving up to 1,000 pre-programmed incremental delays from laser trigger for unrivalled combination of sensitivity and ultra-precise transient phenomena analysis.

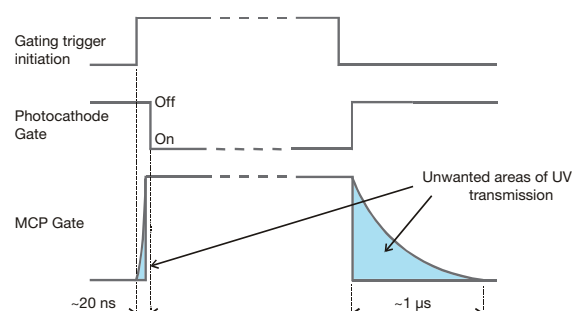
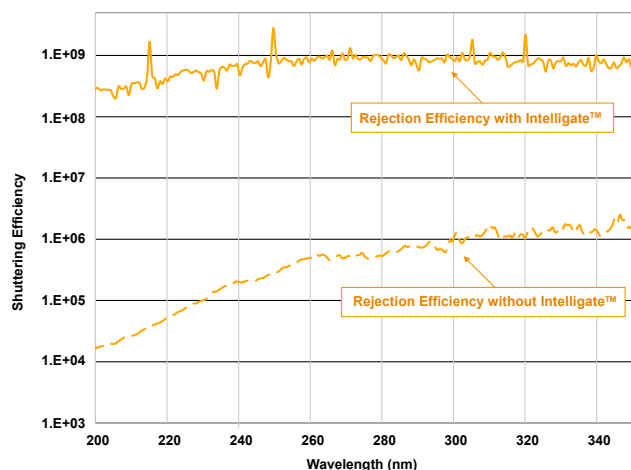


Intelligate™: Superior gating in the UV-VUV region

One of the key functions of an image intensifier is to provide high optical shuttering (ON/OFF) ratio. By switching photocathode voltage to a higher or lower level relative to the MCP voltage, photo-electrons can be either directed towards or repelled from the MCP to avoid detection. ON/OFF values of $1:10^8$ are typically measured for Visible/NIR incident light on the photocathode.

However photocathode "leakage" becomes more pronounced in the UV-VUV region (< 300 nm), where more energetic photons have a greater probability to go through the photocathode turned "OFF", reach the MCP to generate an electron that can be detected. This can lead to shuttering efficiency as low as $1:10^4$.

Andor's exclusive Intelligate™ simultaneously gates the photocathode and the MCP. The ultra fast rising edge of the MCP gate pulse switches on the correct potential in a nanosecond timeframe, coinciding precisely with the photocathode gating pulse. This enables ON/OFF ratios as high as 10^8 in the UV-VUV region.



Creating the optimum product for you



ISTAR-SCMOS-18 F -03
example shown

Step 1. Choose the intensifier diameter

Intensifier Diameter

| Intensifier diameter | Code |
|----------------------|------|
| Ø 18 mm | 18 |
| Ø 25 mm | 25 |

Step 2. Choose a minimum gating speed

Gating Speed

| Gating Speed | Code |
|----------------------|------|
| High QE, slow gating | H |
| Fast Gating | F |
| Ultra Fast Gating | U |

Step 3. Select an image intensifier option

Intensifier

| Gen 2 Intensifier option | Code | Gen 3 Intensifier option | Code |
|---|------|--------------------------------|------|
| W-AGT photocathode, P43 phosphor | 03 | HVS photocathode, P43 phosphor | 63 |
| W-AGT photocathode, P46 phosphor | 04 | VIH photocathode, P43 phosphor | 73 |
| W-AGT photocathode, MgF ₂ window, P43 phosphor | 05 | NIR photocathode, P43 phosphor | 93 |
| WR photocathode, P43 phosphor | 13 | EVS photocathode, P43 phosphor | A3 |
| UW photocathode, P43 phosphor | 83 | BGT photocathode, P43 phosphor | C3 |
| WE-AGT photocathode, P43 phosphor | E3 | | |

All photocathode types can be combined with a fast-decay P46 phosphor – please contact your local Andor representative for further information

Step 4. Select the required accessories and adapters

Accessories & Adapters

| Description | Order Code |
|--|-----------------------|
| C-mount lens adaptor | LM-C |
| F-mount lens adaptor | LM-NIKON-F |
| Oasis 160 Ultra compact chiller unit | ACC-XW-CHIL-160 |
| UV-VIS 105mm SLR lens, 250 - 650 nm transmission, F-mount | OL-AF10-F45-#UV |
| 6 mm tubing option for ACC-XW-CHIL-160 | ACC-6MM-TUBING-2xxxxM |
| i ² c to BNC cable for Shamrock shutter control | ELC-05323 |
| Metric Bracket | ACC-ISTAR-METRIC ADP |
| 15 m active USB 3.0 connector cable (power supply not required) | ACC-ASE-06887 |
| 50 m fibre optic USB 3.0 extender solution including power supply | ACC-ASE-08762 |
| 100 m fibre optic USB 3.0 extender solution including power supply | ACC-ASE-07860 |

Step 5. Select the required software

Software

The iStar sCMOS requires at least one of the following software options:

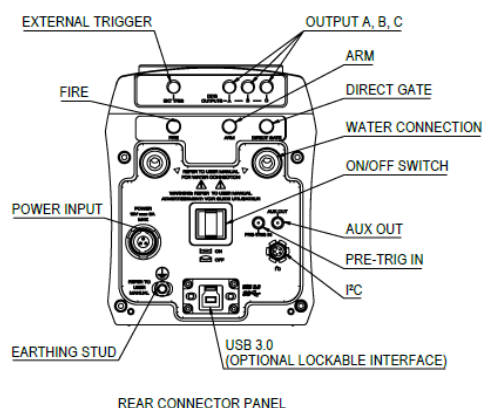
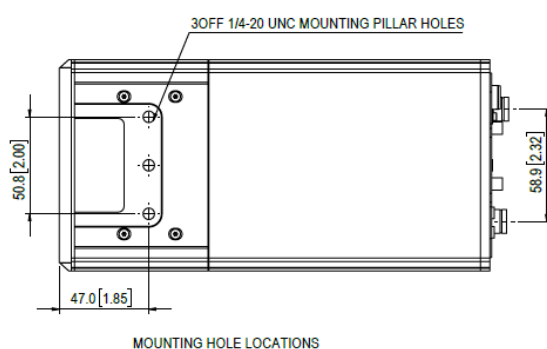
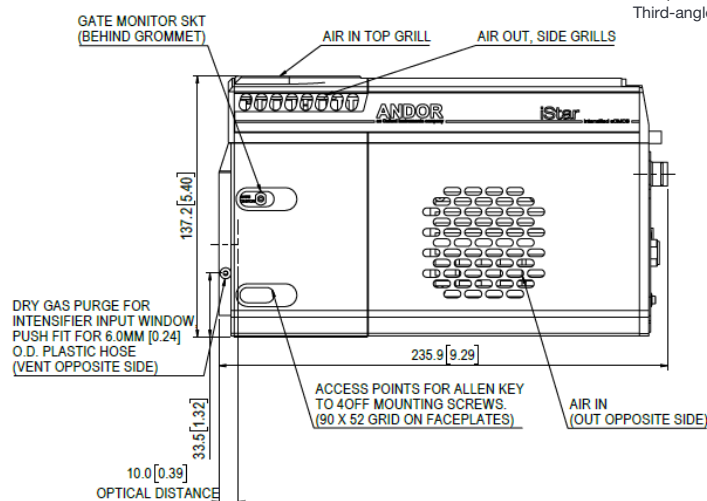
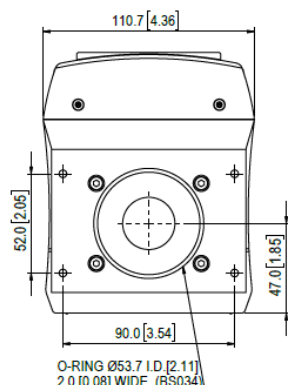
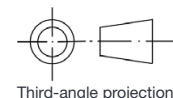
Solis for Time-Resolved A 32-bit and fully 64-bit enabled application for Windows (XP, Vista, 7 and 8) offering rich functionality for data acquisition and processing. AndorBasic provides macro language control of data acquisition, processing, display and export.

Andor SDK3 A software development kit that allows you to control the Andor sCMOS cameras from your own application. Available as 32 and 64-bit libraries for Windows (7 and 8) and Linux. Compatible with C/C++, LabView and Matlab.

GPU Express Andor GPU Express library has been created to simplify and optimize data transfers from camera to a CUDA-enabled NVidia Graphical Processing Unit (GPU) card to facilitate accelerated GPU processing as part of the acquisition pipeline. Integrates easily with Andor SDK3 for Windows.

Product drawings

Dimensions in mm [inches]



Weight: 4.5 kg [9 lb 15 oz]

REGULATORY COMPLIANCE

- RoHS compliant
- EU EMC Directive
- EU LV Directive
- IEC 61010-1 CB Scheme

EXTERNAL POWER SUPPLY COMPLIANCE

- UL-certified for Canada and USA
- Japanese PSE Mark

POWER SUPPLY REQUIREMENTS

- Power: +12 VDC \pm 5% @ 5A typ. / 9A max.
- Ripple: 120 mV peak-peak 0 - 20 MHz
- 100 - 240 VAC, 43 - 67 Hz External power supply
- Power Consumption:
 - Camera + External Power Supply (Typ./ Max.): 69 W/ 124 W
 - Camera Only (Typ./ Max.): 60 W/ 108 W

Connecting to the iStar sCMOS

Camera Control

Connector type: USB 3.0*13

Logic Input / Output

Connector type: SMA, provided with SMA - BNC cable
 6x outputs: FIRE pulse, Output A, B, C from DDG, ARM, and Aux Out.
 3x inputs: Camera trigger from 3rd party source (External Trigger), direct gate for direct external control of intensifier gating, and Pre-Trigger

I²C connector

Compatible with Fischer SC102A054-130, pin-outs as follow:
 1 = Shutter (5V CMOS level with 50 Ω impedance), 2 = I²C Clock (5V), 3 = I²C Data (5V), 4 = +5 Vdc, 5 = Ground

Gate Monitor

1x output: AC coupling to photocathode

Aux Out (external mechanical shutter output)

Configured by default to a 5V CMOS level with 50 Ω impedance shutter output for controlling Andor Shamrock spectrograph mechanical shutters

Pre-trigger

Controls the sensor exposure in 'external exposure mode'. Also available in 'external trigger mode' as a optional exclusive trigger to the sensor.



ORDER TODAY

Need more information? At Andor we are committed to finding the correct solution for you. With a dedicated team of technical advisors, we are able to offer you one-to-one guidance and technical support on all Andor products. For a full listing of our regional sales offices, please see: andor.com/contact

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ITEMS SHIPPED WITH YOUR CAMERA

- 1 x USB 3.0 PCIe Card and 1 x 3 m USB 3.0 cable (Type A to B)
- 1x Gate Monitor cable
- 2x 2 m BNC to SMA cable
- 1x Power supply with mains cable
- 1x Quick Start Guide
- 1x CD containing Andor user guides

Footnotes: Specifications are subject to change without notice

1. Note that the write speed of the PC hard drive can impose a further restriction to achieving sustained kinetic series acquisition.
2. Figures are typical unless otherwise stated.
3. Readout noise is for the entire system and is taken as a median over the sensor area excluding any regions of blemishes. It is a combination of sensor readout noise and A/D noise.
4. Dark current measurement is taken as a median over the sensor area excluding any regions of blemishes.
5. Linearity is measured from a plot of Signal vs. Exposure Time over the full dynamic range.
6. The On/Off ratio for the 'E3' image intensifier in the UV with MCP gating is typically 10^5 .
7. Typical photocathode Quantum Efficiency and input window transmission as measured by the tube manufacturer.
8. Typical resolution of the image intensifier tube only, not the overall resolution of the system. As a rough guide, the smallest resolvable FWHM feature will be approximately 4x the sensor pixel size. This is a very important consideration for optical resolution calculations in spectrograph-based systems.
9. Gen 2 High QE (H) option – Photocathode QE is inherently linked to the gating speed of the intensifier. High QE option (H) offers higher peak QE than Ultrafast (U) or Fast (F) intensifiers, while exhibiting minimum gating speed one order of magnitude slower.
10. Actual measured minimum optical gating of the photocathode, reflecting not only the electrical pulse width applied to the photocathode but also its inherent iris time.
11. Gain is software-selectable through a 12-bit DAC and varies exponentially with DAC setting. Value refers to the ratio of max to min intensifier gain as measured for individual cameras. Actual optical gain (counts/ photoe) for a DAC setting is accessed by the multiplication of the relative gain (at that DAC value) by the minimum system gain (at DAC = 0, sCMOS e⁻/photoe) and divided by the sCMOS sensitivity (sCMOS e⁻/count). Sensitivities are individually measured and reported for each system.
12. Combination of -73 GaAsP photocathode with a lumogen-coated fibre-optic plate and protective MgF2 window. The latter additional optical interfaces are the reason for the lowered QE in the visible NIR region, for the -C3 model. Note that spectral resolution will be degraded < 450 nm.
13. USB 3.0 connection should work with any modern USB 3.0 enabled PC/laptop (provided hard drives or RAM is sufficient to support data rates) as every USB 3.0 port should have its own host controller. iStar sCMOS also ship with a USB 3.0 PCIe card as a means to add a USB 3.0 port to an older PC, or as a diagnostic aid to interoperability issues or to ensure maximum speed.



MINIMUM COMPUTER REQUIREMENTS:

- 2.68 GHz Quad Core
- 4GB RAM (increase RAM if to be used for continuous data spooling)
- Hard Drive: Minimum 450 MB/s continuous write
- PCI Express x4 or greater
- Windows (7 or 8) or Linux
- * See technical note entitled: 'PC Specifications for sCMOS'

Operating and Storage Conditions

- Operating Temperature: 0°C to 40°C ambient
- Relative Humidity: < 70% (non-condensing)
- Storage Temperature: -20°C to 55°C

Power Requirements

- Please refer to page 9



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